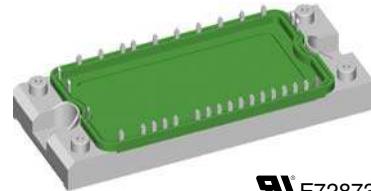
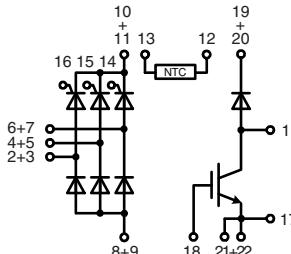


## Three Phase Rectifier Bridge with IGBT and Fast Recovery Diode for Braking System

**V<sub>RRM</sub> = 1600 V**  
**I<sub>dAVM</sub> = 170 A**

V <sub>RRM</sub>	Type
V	
1600	VVZB 170-16 NO1



E72873

See outline drawing for pin arrangement

Symbol	Conditions	Maximum Ratings		
V <sub>RRM</sub>	T <sub>C</sub> = 85°C; sinusoidal 120°	1600	V	
I <sub>dAVM</sub>		170	A	
I <sub>FSM</sub>	T <sub>VJ</sub> = 45°C; t = 10 ms; V <sub>R</sub> = 0 V	900	A	
	T <sub>VJ</sub> = 150°C; t = 10 ms; V <sub>R</sub> = 0 V	780	A	
I <sup>2</sup> t	T <sub>VJ</sub> = 45°C; t = 10 ms; V <sub>R</sub> = 0 V	4050	A	
	T <sub>VJ</sub> = 150°C; t = 10 ms; V <sub>R</sub> = 0 V	3040	A	
P <sub>tot</sub>	T <sub>C</sub> = 25°C per diode	250	W	
(di/dt) <sub>cr</sub>	Rectifier Bridge	150	A/μs	
	T <sub>VJ</sub> = T <sub>VJM</sub> ; repetitive; I <sub>T</sub> = 150 A			
	f = 50 Hz; t <sub>P</sub> = 200 μs;			
	V <sub>D</sub> = 2/3 V <sub>DRM</sub> ;			
	I <sub>G</sub> = 0.45 A; non repetitive; I <sub>T</sub> = I <sub>d(AV)</sub> /3	500	A/μs	
	di <sub>G</sub> /dt = 0.45 A/μs			
(dv/dt) <sub>cr</sub>		1000	V/μs	
	T <sub>VJ</sub> = T <sub>VJM</sub> ; V <sub>DR</sub> = 2/3 V <sub>DRM</sub> ;			
	R <sub>GR</sub> = ∞; method 1 (linear voltage rise)			
P <sub>GM</sub>	T <sub>VJ</sub> = T <sub>VJM</sub> ; t <sub>P</sub> = 30 μs	10	W	
	I <sub>T</sub> = I <sub>d(AV)</sub> /3; t <sub>P</sub> = 300 μs	5	W	
P <sub>GAVM</sub>		0.5	W	
V <sub>CES</sub>	T <sub>VJ</sub> = 25°C to 150°C	1200	V	
V <sub>GE</sub>	Continuous	± 20	V	
I <sub>C25</sub>	T <sub>C</sub> = 25°C; DC	141	A	
I <sub>C80</sub>	T <sub>C</sub> = 80°C; DC	100	A	
I <sub>CM</sub>	t <sub>p</sub> = Pulse width limited by T <sub>VJM</sub>	150	A	
P <sub>tot</sub>	T <sub>C</sub> = 25°C	570	W	
V <sub>RRM</sub>		1200	V	
I <sub>FAV</sub>	T <sub>C</sub> = 80°C; rectangular d = 0.5	27	A	
I <sub>FRMS</sub>	T <sub>C</sub> = 80°C; rectangular d = 0.5	38	A	
I <sub>FRM</sub>	T <sub>C</sub> = 80°C; t <sub>p</sub> = 10 μs; f = 5 kHz	tbd	A	
I <sub>FSM</sub>	T <sub>VJ</sub> = 45°C; t = 10 ms	200	A	
P <sub>tot</sub>	T <sub>C</sub> = 25°C	130	W	

### Features

- Soldering connections for PCB mounting
- Convenient package outline
- Thermistor

### Applications

- Drive Inverters with brake system

### Advantages

- 2 functions in one package
- Easy to mount with two screws
- Suitable for wave soldering
- High temperature and power cycling capability

**Recommended replacement:**

**VVZB 170-16ioXT**

Data according to IEC 60747

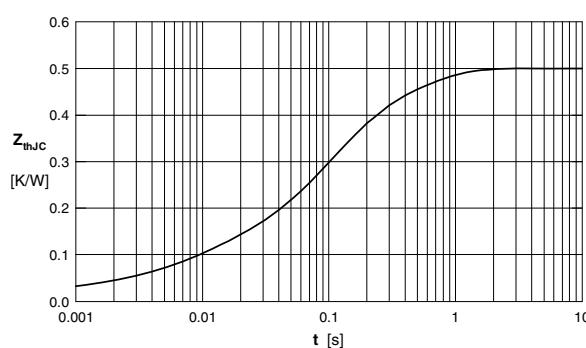
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Symbol	Conditions	Characteristic Values ( $T_{VJ} = 25^\circ\text{C}$ , unless otherwise specified)		
		min.	typ.	max.
$I_R, I_D$	$V_R = V_{RRM}; T_{VJ} = 25^\circ\text{C}$ $V_R = V_{RRM}; T_{VJ} = 150^\circ\text{C}$		0.1 mA 20 mA	
$V_F, V_T$	$I_F = 150 \text{ A}; T_{VJ} = 25^\circ\text{C}$		1.68 V	
$V_{TO}$ $r_T$	for power-loss calculations only $T_{VJ} = 150^\circ\text{C}$		0.85 V 5.9 mΩ	
$V_{GT}$	$V_D = 6 \text{ V}; T_{VJ} = 25^\circ\text{C}$ $T_{VJ} = -40^\circ\text{C}$		1.5 V 1.6 V	
$I_{GT}$	$V_D = 6 \text{ V}; T_{VJ} = 25^\circ\text{C}$ $T_{VJ} = -40^\circ\text{C}$		95 mA 200 mA	
$V_{GD}$ $I_{GD}$	$T_{VJ} = T_{VJM}; V_D = \frac{2}{3} V_{DRM}$ $T_{VJ} = T_{VJM}; V_D = \frac{2}{3} V_{DRM}$		0.2 V 10 mA	
$I_L$	$V_D = 6 \text{ V}; t_g = 10 \mu\text{s};$ $di_g/dt = 0.45 \text{ A}/\mu\text{s}; I_G = 0.45 \text{ A}$		450 mA	
$I_H$	$T_{VJ} = T_{VJM}; V_D = 6 \text{ V}; R_{GK} = \infty$		200 mA	
$t_{gd}$	$V_D = \frac{1}{2} V_{DRM};$ $di_g/dt = 0.45 \text{ A}/\mu\text{s}; I_G = 0.45 \text{ A}$		2 μs	
$t_q$	$T_{VJ} = T_{VJM}; V_R = 100 \text{ V}; V_D = \frac{2}{3} V_{DRM};$ $t_p = 200 \mu\text{s}; dv/dt = 20 \text{ V}/\mu\text{s};$ $I_T = 120 \text{ A}; -di/dt = 10 \text{ A}/\mu\text{s}$		150 μs	
$R_{thJC}$ $R_{thCH}$	per rectifier		0.5 K/W 0.1 K/W	
$V_{BR(CES)}$ $V_{GE(th)}$	$V_{GS} = 0 \text{ V}; I_C = 0.1 \text{ mA}$ $I_C = 3 \text{ mA}$	1200 4.5	V V	
$I_{CES}$	$V_{CE} = 1200 \text{ V}; T_{VJ} = 25^\circ\text{C}$ $V_{CE} = 0.8 \cdot V_{CES}; T_{VJ} = 125^\circ\text{C}$		0.1 mA 0.5 mA	
$V_{CEsat}$	$V_{GE} = 15 \text{ V}; I_C = 150 \text{ A}$		3.7 V	
$t_{SC} (SCSOA)$	$V_{GE} = 15 \text{ V}; V_{CE} = 900 \text{ V}; T_{VJ} = 125^\circ\text{C}$		10 μs	
<b>RBSOA</b>	$V_{GE} = 15 \text{ V}; V_{CE} = 1200 \text{ V}; T_{VJ} = 125^\circ\text{C};$ clamped inductive load; $L = 100 \mu\text{H};$ $R_G = 15 \Omega$		150 A	
$C_{ies}$	$V_{CE} = 25 \text{ V}; f = 1 \text{ MHz}; V_{GE} = 0 \text{ V}$		5.7 nF	
$t_{d(on)}$ $t_{d(off)}$ $E_{on}$ $E_{off}$	$\left. \begin{array}{l} V_{CE} = 720 \text{ V}; I_C = 75 \text{ A}; \\ V_{GE} = 15 \text{ V}; R_G = 15 \Omega; \end{array} \right\}$ Inductive load; $L = 100 \mu\text{H};$ $T_{VJ} = 125^\circ\text{C}$	150 ns 680 ns 9 mJ 7.5 mJ		
$R_{thJC}$ $R_{thCH}$		0.4	0.22 K/W 0.4 K/W	



	$R_i$	$\tau_i$
1	0.02308	0.0004
2	0.06385	0.007
3	0.2777	0.092
4	0.1354	0.44

Fig. 1 Transient thermal impedance junction to case (per thyristor/diode)

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Symbol	Conditions	Characteristic Values ( $T_{VJ} = 25^\circ\text{C}$ , unless otherwise specified)		
		min.	typ.	max.
$I_R$	$V_R = V_{RRM}$ , $T_{VJ} = 25^\circ\text{C}$ $V_R = 1200 \text{ V}$ , $T_{VJ} = 125^\circ\text{C}$	1	0.25 mA	mA
$V_F$	$I_F = 30 \text{ A}$ , $T_{VJ} = 25^\circ\text{C}$		2.76 V	
$V_{TO}$	For power-loss calculations only		1.3 V	
$r_T$	$T_{VJ} = 150^\circ\text{C}$		16 mΩ	
$I_{RM}$	$I_F = 50 \text{ A}$ , $-di_F/dt = 100 \text{ A}/\mu\text{s}$ , $V_R = 100 \text{ V}$	5.5	11 A	
$t_{rr}$	$I_F = 1 \text{ A}$ , $-di_F/dt = 200 \text{ A}/\mu\text{s}$ , $V_R = 30 \text{ V}$	40		ns
$R_{thJC}$			0.9 K/W	
$R_{thCH}$			0.1 K/W	
$R_{25}$	$\text{NTC}$	$\left\{ R(T) = R_{25} \cdot e^{B_{25/100} \left( \frac{1}{T} - \frac{1}{298K} \right)} \right\}$	4.75	5.0 kΩ
$B_{25/50}$			3375	K

Symbol	Conditions	Maximum Ratings	
$T_{VJ}$		-40...+150	°C
$T_{VJM}$		150	°C
$T_{stg}$		-40...+125	°C
$V_{ISOL}$	50/60 Hz, $t = 1 \text{ min}$ $I_{ISOL} \leq 1 \text{ mA}$ , $t = 1 \text{ s}$	2500 V~ 3000 V~	
$M_d$	Mounting torque	2.7...3.3	Nm
$d_s$	Creep distance on surface	12.7	mm
$d_A$	Strike distance in air	9.6	mm
$a$	Maximum allowable acceleration	50	$\text{m/s}^2$
Weight	typ.	180	g

Dimensions in mm (1 mm = 0.0394")

